



S1A THRU S1M

1.0 AMP. Surface Mount Rectifiers



Voltage Range
50 to 1000 Volts
Current
1.0 Ampere

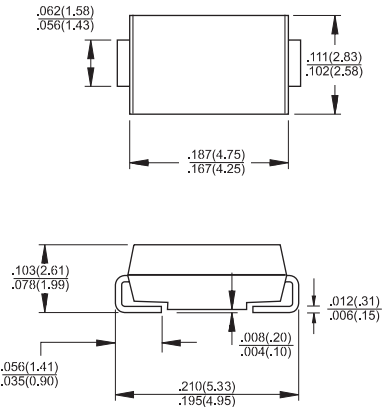
SMA/DO-214AC

Features

- ✧ For surface mounted application
- ✧ Glass passivated junction chip.
- ✧ Low forward voltage drop
- ✧ High current capability
- ✧ Easy pick and place
- ✧ High surge current capability
- ✧ Plastic material used carries Underwriters Laboratory Classification 94V-O
- ✧ High temperature soldering: 260°C / 10 seconds at terminals

Mechanical Data

- ✧ Case: Molded plastic
- ✧ Terminals: Solder plated
- ✧ Polarity: Indicated by cathode band
- ✧ Packaging: 12mm tape per EIA STD RS-481
- ✧ Weight: 0.064 gram



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	S1A	S1B	S1D	S1G	S1J	S1K	S1M	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current @ $T_L = 110^\circ\text{C}$	$I_{(AV)}$	1.0							A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	30							A
Maximum Instantaneous Forward Voltage @ 1.0A	V_F	1.1							V
Maximum DC Reverse Current @ $T_A = 25^\circ\text{C}$ at Rated DC Blocking Voltage @ $T_A = 125^\circ\text{C}$	I_R	5 50							μA μA
Typical Thermal Resistance (Note 3)	$R_{\theta JL}$ $R_{\theta JA}$	27 75					30 85		$^\circ\text{C}/\text{W}$
Maximum Reverse Recovery Time (Note 1)	T_{rr}	1.8							μS
Typical Junction Capacitance (Note 2)	C_j	12							pF
Operating Temperature Range	T_J	-55 to +150							$^\circ\text{C}$
Storage Temperature Range	T_{STG}	-55 to +150							$^\circ\text{C}$

Notes: 1. Reverse Recovery Test Conditions: $I_F = 0.5\text{A}$, $I_R = 1.0\text{A}$, $I_{RR} = 0.25\text{A}$

2. Measured at 1 MHz and Applied $V_R = 4.0$ Volts

3. Measured on P.C. Board with 0.2 x 0.2" (5.0 x 5.0mm) Copper Pad Areas.

RATINGS AND CHARACTERISTIC CURVES (SIA THRU SIM)

FIG.1- MAXIMUM FORWARD CURRENT DERATING CURVE

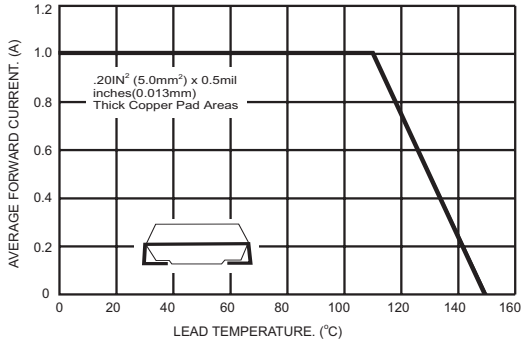


FIG.2- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

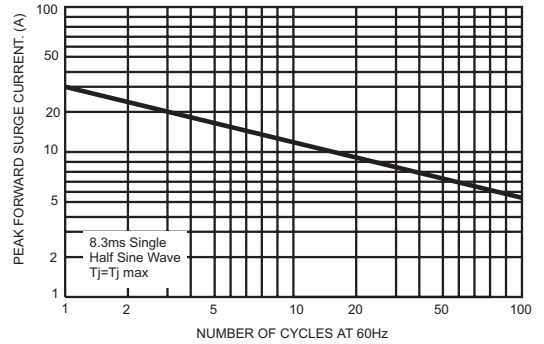


FIG.3- TYPICAL FORWARD CHARACTERISTICS

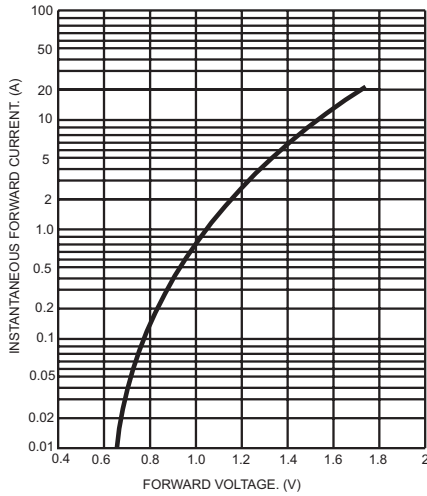


FIG.4- TYPICAL REVERSE CHARACTERISTICS

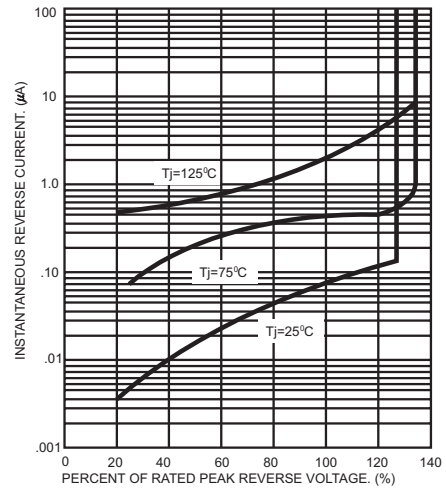


FIG.5- TYPICAL JUNCTION CAPACITANCE

